

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Smith et al.

Serial No.: 09/975,639

Filed: 10/11/01

Docket No.: TI-29811

Art Unit: 2818

Examiner: Hoang, Quoc

Title: Hydrogen Plasma Photoresist Strip And Polymeric Residue Cleanup Process

For Low Dielectric Constant Materials

**AMENDMENT UNDER 37 CFR 1.111** 

June 6, 2002

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action, dated 03/14/03, in the above-identified patent application, please make the following amendments. They are respectfully submitted as a full and complete response to that Action. Charge any required fees to the deposit account of Texas Instruments Incorporated, Account No. 20-0668.